NSN 5961-01-120-5205

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View Online at https://aerobasegroup.com/nsn/5961-01-120-5205 **Inclosure Material:** Metal **Overall Length:** 0.105 inches Overall Diameter: 0.105 inches **End Application:** 1425-01-066-7775 **Internal Configuration:** Junction contact **Internal Junction Configuration:** Npn **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 25.0 collector to base voltage/static/emitter open and 15.0 collector to emitter voltage/static/base open and 3.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 30.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 300.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 4 ribbon **Specification Data:** 81349-mil-s-19500/522 government specification Shelf Life: N/a **Unit Of Measure:**

Fiig: A110a0

No

Demilitarization: